ELSEVIER

Thin Solid Films 339 (1999) 320–321

thin solid films

Author Index of Volume 339

Abd Alla, R.A., 314

Bae, B.J., 200
Balaji, T., 187
Basu, M., 44
Borisov, S.V., 129
Bowsek, J., 216
Brett, M.J., 88

Carter, C.B., 117
Cesarano III, J., 209
Chaffa, A., 10
Chang, C.S., 294
Chang, Y.R., 1
Chaudhuri, S., 44
Chen, C.Y., 294
Chen, G., 58
Chen, J.Z., 194
Chen, X.H., 6
Chen, Z.Y., 74
Chen, Z.Z., 6
Cheng, F., 109
Chow, L., 148
Chvostova, D., 216

Dai, Z., 114
Daran, E., 187
Deineka, A.G., 216
Denisov, O.F., 129
DeVriesl, R.C., 19
Dew, S.K., 88
Ding, Y., 6
Dong, S., 277
Dubourdieu, C., 165

El Zawawi, I.K., 314

Fan, Y-D., 95
Federici, J., 102
Feng, S.Q., 6
Friedrich, L.J., 88
Fujita, M., 309
Fujiwara, S., 38
Fukawa, M., 220

Gallois, B., 165
Gan, Z-Q., 34
Gao, W., 78
Ge, S-B., 34
George, M.A., 102
Gong, H., 78
Goodson, K.E., 160
Grebel, H., 102
Gribelyuk, M.A., 51

Hale, J.S., 174
Hara, M., 142
Hayashi, Y., 220
Hazel, J.L., 249
Healy, M.J., 299
Hegemann, D., 154
Hessel, V., 284
Hidalgo, M.L., 10
Ho, P.S., 68
Hölsä, J., 240
Hong, C.W., 1
Hotta, S., 120, 137
Hsieh, J-L., 265
Huang, L., 78
Huang, W.C., 294
Hui, P., 58
Huo, Y., 305
Hurd, A.J., 209
Hwang,, B.J., 233

Iqbal, Z., 102
Ishida, T., 142

Jagannadham, K., 19
Jastrabík, L., 216
Ji, M-R., 34
Johnson, M.T., 117
Ju, Y.S., 160
Juliet, P., 240

Kang, S.B., 165
Kang, T.W., 290
Kawano, H., 225
Kesri, N., 10
Kim, B., 200
Kim, J.H., 200
Kim, K.K., 38
Kim, K.N., 290
Kim, Y., 200
Kleiman, J.I., 38
Knoll, W.142
Koga, Y., 38
Kokai, F., 38
Komanduri, R., 19
Koski, K., 240
Kozuka, H., 123
Kulesha, G., 165
Kundu, S.N., 44
Kurabayashi, K., 160
Kuznetsov, M.V., 129
Kwak, M.Y., 290

Lachab, M., 10
Lacoste, G., 187
Lane, D.W., 299
Lee, M.K 1
Legros, R., 187
Lemoine, P., 258
Li, Y.Q., 165
Lia, C-Y., 265
Liao, C., 109
Lifante, G., 187
Lin, H., 123
Liou, H-C., 68
Liu, S., 277
Liu, X.H., 74
Liu, Y.C., 233
Llinarès, C., 10
Löffler, F., 181
Lour, W-S., 265
Lue, J.T., 294
Luo, E.Z., 74
Luo, H., 305

Macda, T., 225
Makino, Y., 203
Mallika, K., 19
Matsumoto, K., 220
Mc Laughlin, J., 258
Miyashita, A., 114
Morikawa, H., 309
Muguruma, H., 120, 137

Naramoto, H., 114
Narum, K., 114
Nishida, N., 142
Nogi, K., 203
Nose, M., 203

Oehr, C.154
Oladeji, I.O., 148
Oswald, M., 284
Ozsan, M.E., 299

Painter, J.D., 299
Pal, A.K., 44
Park, J.E., 200
Park, J.T., 200
Peng, J.C., 6
Peng, Z., 109

Ramamohan, T., 19
Ramesham, R., 82
Rhee, S-W., 270
Riedel, R., 154, 284
Robbie, K., 88
Rogers, K.D., 299

Sasabe, H., 142
Sasaki, D.Y., 209
Seto, M., 88
Shalaeva, E.V., 129
Shan, F., 305
Shen, M-R., 34
Shi, T.S., 74
Shin, D.H., 290
Singh, S., 209
Smy, T., 88
Stierman, R., 68

Takeda, S., 220
Tang, Z., 277
Tarasenko, A.A., 216
Tsukruk, V.V., 249
Tsuneda, S., 142

Vick, D., 88
Vijayalakshmi, S., 102

Wang, E., 277
Wang, Y., 305
Wei, S.J., 1
Wilk, G.D., 51

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ELSEVIER

Thin Solid Films 339 (1999) 320–321

thin solid films

Author Index of Volume 339

Abd Alla, R.A., 314

Bae, B.J., 200
Balaji, T., 187
Basu, M., 44
Borisov, S.V., 129
Bowsek, J., 216
Brett, M.J., 88

Carter, C.B., 117
Cesarano III, J., 209
Chaffa, A., 10
Chang, C.S., 294
Chang, Y.R., 1
Chaudhuri, S., 44
Chen, C.Y., 294
Chen, G., 58
Chen, J.Z., 194
Chen, X.H., 6
Chen, Z.Y., 74
Chen, Z.Z., 6
Cheng, F., 109
Chow, L., 148
Chvostova, D., 216

Dai, Z., 114
Daran, E., 187
Deineka, A.G., 216
Denisov, O.F., 129
DeVriesl, R.C., 19
Dew, S.K., 88
Ding, Y., 6
Dong, S., 277
Dubourdieu, C., 165

El Zawawi, I.K., 314

Fan, Y-D., 95
Federici, J., 102
Feng, S.Q., 6
Friedrich, L.J., 88
Fujita, M., 309
Fujiwara, S., 38
Fukawa, M., 220

Gallois, B., 165
Gan, Z-Q., 34
Gao, W., 78
Ge, S-B., 34
George, M.A., 102
Gong, H., 78
Goodson, K.E., 160
Grebel, H., 102
Gribelyuk, M.A., 51

Hale, J.S., 174
Hara, M., 142
Hayashi, Y., 220
Hazel, J.L., 249
Healy, M.J., 299
Hegemann, D., 154
Hessel, V., 284
Hidalgo, M.L., 10
Ho, P.S., 68
Hölsä, J., 240
Hong, C.W., 1
Hotta, S., 120, 137
Hsieh, J-L., 265
Huang, L., 78
Huang, W.C., 294
Hui, P., 58
Huo, Y., 305
Hurd, A.J., 209
Hwang,, B.J., 233

Iqbal, Z., 102
Ishida, T., 142

Jagannadham, K., 19
Jastrabík, L., 216
Ji, M-R., 34
Johnson, M.T., 117
Ju, Y.S., 160
Juliet, P., 240

Kang, S.B., 165
Kang, T.W., 290
Kawano, H., 225
Kesri, N., 10
Kim, B., 200
Kim, J.H., 200
Kim, K.K., 38
Kim, K.N., 290
Kim, Y., 200
Kleiman, J.I., 38
Knoll, W.142
Koga, Y., 38
Kokai, F., 38
Komanduri, R., 19
Koski, K., 240
Kozuka, H., 123
Kulesha, G., 165
Kundu, S.N., 44
Kurabayashi, K., 160
Kuznetsov, M.V., 129
Kwak, M.Y., 290

Lachab, M., 10
Lacoste, G., 187
Lane, D.W., 299
Lee, M.K 1
Legros, R., 187
Lemoine, P., 258
Li, Y.Q., 165
Lia, C-Y., 265
Liao, C., 109
Lifante, G., 187
Lin, H., 123
Liou, H-C., 68
Liu, S., 277
Liu, X.H., 74
Liu, Y.C., 233
Llinarès, C., 10
Löffler, F., 181
Lour, W-S., 265
Lue, J.T., 294
Luo, E.Z., 74
Luo, H., 305

Macda, T., 225
Makino, Y., 203
Mallika, K., 19
Matsumoto, K., 220
Mc Laughlin, J., 258
Miyashita, A., 114
Morikawa, H., 309
Muguruma, H., 120, 137

Naramoto, H., 114
Narum, K., 114
Nishida, N., 142
Nogi, K., 203
Nose, M., 203

Oehr, C.154
Oladeji, I.O., 148
Oswald, M., 284
Ozsan, M.E., 299

Painter, J.D., 299
Pal, A.K., 44
Park, J.E., 200
Park, J.T., 200
Peng, J.C., 6
Peng, Z., 109

Ramamohan, T., 19
Ramesham, R., 82
Rhee, S-W., 270
Riedel, R., 154, 284
Robbie, K., 88
Rogers, K.D., 299

Sasabe, H., 142
Sasaki, D.Y., 209
Seto, M., 88
Shalaeva, E.V., 129
Shan, F., 305
Shen, M-R., 34
Shi, T.S., 74
Shin, D.H., 290
Singh, S., 209
Smy, T., 88
Stierman, R., 68

Takeda, S., 220
Tang, Z., 277
Tarasenko, A.A., 216
Tsukruk, V.V., 249
Tsuneda, S., 142

Vick, D., 88
Vijayalakshmi, S., 102

Wang, E., 277
Wang, Y., 305
Wei, S.J., 1
Wilk, G.D., 51

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PII: S0040-6090(98)01777-5

Wilson, I.H., 74
Woollam, J.A., 174
Wu, S.K., 194

Xin, Y., 34
Xu, J.B., 74
Xu, Z., 109

Yamamoto, K., 38
Yamamoto, S., 114
Yan, C., 109
Yang, S.Q., 74
Yoko, T., 123
Yu, K-S., 200
Yu, Y.H., 74

Yudasaka, M., 120
Yun, J-H., 270

Zhao, G., 123
Zhao, J.P., 74
Zhou, M., 203
Zhou, Z-F., 95
Zhu, P., 114
Zhu, Y.Y., 225
Zouaoui, A., 10

ELSEVIER

Thin Solid Films 339 (1999) 322–327

thin solid films

Subject Index of Volume 339

Adsorption
Surface OH group governing adsorption properties of metal oxide films, 220
Air–water interface
Formation of ultra-thin ceramic TiO_2 films by the Langmuir–Blodgett technique – a two-dimensional sol-gel process at the air–water interface, 284
Alkali halide
Positive-ionic and neutral-molecular desorptions by temperature-programmed heating of a thin film of lithium bromide, 225
Alkylsiloxane monolayer
Nanometer pores in ultrathin silica films prepared by self-assembly of organic spacers in an alkylsiloxane monolayer, 209
Alloy
Structural analysis of Co–Cr alloy films by X-ray diffraction, 95
Aluminium nitride
AlN films grown by electric field induced flux of Al cations, 117
Growth of AlN films using hydrazidoalane single-source precursors, 200
Aluminium oxide
AlN films grown by electric field induced flux of Al cations, 117
Properties of aluminium oxide thin films deposited by reactive magnetron sputtering, 240
Amorphization
Metastable phase diagram of Ti–Ti–N(O) films ($C_{Si} < 30$ at.%), 129
Amorphous materials
Crystallization behavior of r.f.-sputtered TiNi thin films, 194
Anisotropy
Thermal characterization of anisotropic thin dielectric films using harmonic Joule heating, 160
Annealing
Structural, compositional and photoluminescence characteristics of $CuInSe_2$ thin films prepared by close-spaced vapor transport, 10
Crystallization behavior of r.f.-sputtered TiNi thin films, 194
Arsenic
Electrical and optical phototransformation properties in As doped Se thin films, 314
Atomic force
Spring constants of composite ceramic/gold cantilevers for scanning probe microscopy, 249
Atomic force microscopy
The sol-gel preparation and AFM study of spinel $CoFe_2O_4$ thin film, 109
Nanomechanical measurements on polymers using contact mode atomic force microscopy, 258
Fabrication and characterization of heteropolyanion Langmuir–Blodgett films, 277

Bistable switching
The bistable switching property of a porous-silicon Schottky barrier diode during the charging period, 294
Boron carbonitride
Influence of single-source precursors on PACVD-derived boron carbonitride thin films, 154

Cadmium telluride
The crystal structure of CdS–CdTe thin film heterojunction solar cells, 299
Carbon nanotubes array
The formation conditions of carbon nanotubes array based on FeNi alloy island films, 6
Carbon nitride thin film
Carbon nitride thin films prepared by nitrogen ion assisted pulsed laser deposition of graphite using KrF excimer laser, 38
Catalyst-solvent
On the low pressure transformation of graphite to diamond in the presence of a 'catalyst-solvent', 19
Cavitation testing
Methods to investigate mechanical properties of coatings, 181
Chemical vapor deposition
Structural, compositional and photoluminescence characteristics of $CuInSe_2$ thin films prepared by close-spaced vapor transport, 10
On the low pressure transformation of graphite to diamond in the presence of a 'catalyst-solvent', 19
Vapor polymerization deposition of new polyamide thin films having oligothiophene segments in the main chain, 120
Solid single-source metal organic chemical vapor deposition of yttria-stabilized zirconia, 165
Growth of AlN films using hydrazidoalane single-source precursors, 200
Feature scale simulation of selective chemical vapor deposition process, 270
Coating characterization
Methods to investigate mechanical properties of coatings, 181

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PII: S0040-6090(98)01778-7

Coefficient of thermal expansion
Thickness dependence of the anisotropy in thermal expansion of PMDA-ODA and BPDA-PDA thin films, 68
Complex
Interaction of copper(I)-polypyrrole complexes prepared by depositing–dissolving copper onto and from polypyrroles, 233
Computer simulation
Self-shadowing and surface diffusion effects in obliquely deposited thin films, 88
Conductivity
Crystallization and decrease in resistivity on heat treatment of amorphous indium tin oxide thin films prepared by d.c. magnetron sputtering, 309
Copper indium diselenide film
$CuInSe_2$ films produced by graphite box annealing of multilayer precursors, 44
Crystallization
Crystallization and decrease in resistivity on heat treatment of amorphous indium tin oxide thin films prepared by d.c. magnetron sputtering, 309
Crystallization behavior of r.f.-sputtered TiNi thin films, 194
Thin films prepared by d.c. magnetron sputtering, 309
Cyclic voltammetry
Voltammetric studies at the polycrystalline diamond grown over a graphite electrode material, 82
Fabrication and characterization of heteropolyanion Langmuir–Blodgett films, 277

Deposition process
Self-shadowing and surface diffusion effects in obliquely deposited thin films, 88
Depth profiling
The crystal structure of CdS–CdTe thin film heterojunction solar cells, 299
Diamond
On the low pressure transformation of graphite to diamond in the presence of a 'catalyst-solvent', 19
Dimeric hydrazidoalane
Growth of AlN films using hydrazidoalane single-source precursors, 200
Doped-diamond
Voltammetric studies at the polycrystalline diamond grown over a graphite electrode material, 82
Double heterostructure
ZnS_xSe_{1-x} heteroepitaxial growth on GaP by metalorganic vapor phase epitaxy, 1

Elastic properties
Spring constants of composite ceramic/gold cantilevers for scanning probe microscopy, 249
Electrical properties and measurements
Electrical properties of nitrogen incorporated tetrahedral amorphous carbon films, 74
Electrical and optical phototransformation properties in As doped Se thin films, 314
Electrochromic devices
Prospects for IR emissivity control using electrochromic structures, 174
Electrolysis
Preparation of nitrogen-containing carbon films by electrolysis of organic solutions, 34
Ellipsometry
An ellipsometric study of W thin films deposited on Si, 216
Emissivity modulation
Prospects for IR emissivity control using electrochromic structures, 174
Epitaxial growth
Pulsed laser deposition of ilmenite $FeTiO_3$ epitaxial thin film onto sapphire substrate, 114
Etching
Field-effect-transistor and real-space-transfer behaviors by double-heterojunction doped channel, 265
Evaporation
Self-shadowing and surface diffusion effects in obliquely deposited thin films, 88

Feature scale model
Feature scale simulation of selective chemical vapor deposition process, 270
FeNi alloys
The formation conditions of carbon nanotubes array based on FeNi alloy island films, 6
Ferri/ferro cyanide
Voltammetric studies at the polycrystalline diamond grown over a graphite electrode material, 82
$FeTiO_3$
Pulsed laser deposition of ilmenite $FeTiO_3$ epitaxial thin film onto sapphire substrate, 114
Field effect
Field-effect-transistor and real-space-transfer behaviors by double-heterojunction doped channel, 265
Fluorine (Fluorides)
Growth by molecular beam epitaxy and characterization of $CaF_2:Pr^{3+}$ planar waveguides, 187
Fourier transform infrared spectroscopy
Fabrication and characterization of heteropolyanion Langmuir–Blodgett films, 277

Gallium arsenide
Field-effect-transistor and real-space-transfer behaviors by double-heterojunction doped channel, 265
GaP
ZnS_xSe_{1-x} heteroepitaxial growth on GaP by metalorganic vapor phase epitaxy, 1
Gas mixtures
Pulsed laser deposition of ilmenite $FeTiO_3$ epitaxial thin film onto sapphire substrate, 114
Gold
Tailoring of a smooth polycrystalline gold surface as a suitable anchoring site for a self-assembled monolayer, 142
Graphite box annealing
$CuInSe_2$ films produced by graphite box annealing of multilayer precursors, 44
Graphite
On the low pressure transformation of graphite to diamond in the presence of a 'catalyst-solvent', 19

Carbon nitride thin films prepared by nitrogen ion assisted pulsed laser deposition of graphite using KrF excimer laser, 38
Voltammetric studies at the polycrystalline diamond grown over a graphite electrode material, 82
Growth mechanism
Metastable phase diagram of Ti–Ti–N(O) films ($C_{Si} < 30$ at.%), 129
A study of the effects of ammonium salts on chemical bath deposited zinc sulfide thin films, 148

Hardness
Phase transition and properties of Ti–Al–N thin films prepared by r.f.-plasma assisted magnetron sputtering, 203
Properties of aluminium oxide thin films deposited by reactive magnetron sputtering, 240
Nanomechanical measurements on polymers using contact mode atomic force microscopy, 258
Heterostructures
Growth and microstructure of $Si/CaF_2/Si(111)$ heterostructures, 51
High resolution transmission electron microscopy
Growth and microstructure of $Si/CaF_2/Si(111)$ heterostructures, 51

Impact testing
Methods to investigate mechanical properties of coatings, 181
Indium tin oxide
Crystallization and decrease in resistivity on heat treatment of amorphous indium tin oxide thin films prepared by d.c. magnetron sputtering, 309
Inorganic compounds
The sol-gel preparation and AFM study of spinel $CoFe_2O_4$ thin film, 109
A study of the effects of ammonium salts on chemical bath deposited zinc sulfide thin films, 148
Interaction
Interaction of copper(I)-polypyrrole complexes prepared by depositing–dissolving copper onto and from polypyrroles, 233
Ion assisted pulse laser
Carbon nitride thin films prepared by nitrogen ion assisted pulsed laser deposition of graphite using KrF excimer laser, 38
Island films
The formation conditions of carbon nanotubes array based on FeNi alloy island films, 6

KrF excimer laser
Carbon nitride thin films prepared by nitrogen ion assisted pulsed laser deposition of graphite using KrF excimer laser, 38

Langmuir–Blodgett film
Nanometer pores in ultrathin silica films prepared by self-assembly of organic spacers in an alkylsiloxane monolayer, 209
Fabrication and characterization of heteropolyanion Langmuir–Blodgett films, 277
Langmuir–Blodgett technique
Formation of ultra-thin ceramic TiO_2 films by the Langmuir–Blodgett technique – a two-dimensional sol-gel process at the air–water interface, 284
Luminescence
Growth by molecular beam epitaxy and characterization of $CaF_2:Pr^{3+}$ planar waveguides, 187

Maxwell–Garnett and Bruggeman effective medium approximations
An ellipsometric study of W thin films deposited on Si, 216
Mechanical properties
Methods to investigate mechanical properties of coatings, 181
Metal/oxide/silicon capacitor
Characteristics of TiN barrier layer against Cu diffusion, 290
Metallization
Characteristics of TiN barrier layer against Cu diffusion, 290
Metalorganic vapor phase epitaxy
ZnS_xSe_{1-x} heteroepitaxial growth on GaP by metalorganic vapor phase epitaxy, 1
Microstructure
Growth and microstructure of $Si/CaF_2/Si(111)$ heterostructures, 51
Molecular beam epitaxy (MBE)
Growth by molecular beam epitaxy and characterization of $CaF_2:Pr^{3+}$ planar waveguides, 187
Monolayers
Tailoring of a smooth polycrystalline gold surface as a suitable anchoring site for a self-assembled monolayer, 142
Morphology
Morphological and spectroscopic studies of thin films of quaterthiophenes having extra bulky terminal groups, 137
Multilayer optical models
An ellipsometric study of W thin films deposited on Si, 216

Nanostructures
Characterization of laser ablated silicon thin films, 102
Nitrides
AlN films grown by electric field induced flux of Al cations, 117
Nitrogen incorporating
Electrical properties of nitrogen incorporated tetrahedral amorphous carbon films, 74
Nitrogen-containing carbon film
Preparation of nitrogen-containing carbon films by electrolysis of organic solutions, 34

Oligothiophene
Vapor polymerization deposition of new polyamide thin films having oligothiophene segments in the main chain, 120
Optical constants
An ellipsometric study of W thin films deposited on Si, 216

Optical properties
Structural, compositional and photoluminescence characteristics of $CuInSe_2$ thin films prepared by close-spaced vapor transport, 10
Tailoring of a smooth polycrystalline gold surface as a suitable anchoring site for a self-assembled monolayer, 142
Growth by molecular beam epitaxy and characterization of $CaF_2:Pr^{3+}$ planar waveguides, 187
Electrical and optical phototransformation properties in As doped Se thin films, 314
Organic spacer
Nanometer pores in ultrathin silica films prepared by self-assembly of organic spacers in an alkylsiloxane monolayer, 209
Organic substances
Surface OH group governing adsorption properties of metal oxide films, 220
Orientation
Thickness dependence of the anisotropy in thermal expansion of PMDA-ODA and BPDA-PDA thin films, 68
Oxides
Solid single-source metal organic chemical vapor deposition of yttria-stabilized zirconia, 165
Surface OH group governing adsorption properties of metal oxide films, 220

Phase transitions
Phase change of sputtered $LaNi_5$ thin films due to hydrogenation, 78
Phase transition and properties of Ti–Al–N thin films prepared by r.f.-plasma assisted magnetron sputtering, 203
Photoelectrochemistry
Sol-gel preparation of $Ti_{1-x}V_xO_2$ solid solution film electrodes with conspicuous photoresponse in the visible region, 123
Photothermal modeling of composite samples
Pulsed photothermal modeling of composite samples based on transmission-line theory of heat conduction, 58
Photothermal reflectance
Pulsed photothermal modeling of composite samples based on transmission-line theory of heat conduction, 58
Physical vapour deposition
Self-shadowing and surface diffusion effects in obliquely deposited thin films, 88
Properties of aluminium oxide thin films deposited by reactive magnetron sputtering, 240
Polyamide
Vapor polymerization deposition of new polyamide thin films having oligothiophene segments in the main chain, 120
Polycrystalline films
Growth of AlN films using hydrazidoalane single-source precursors, 200
Polyimides
Thickness dependence of the anisotropy in thermal expansion of PMDA-ODA and BPDA-PDA thin films, 68
Polymers
Nanomechanical measurements on polymers using contact mode atomic force microscopy, 258
Porous silicon Schottky barrier
The bistable switching property of a porous-silicon Schottky barrier diode during the charging period, 294
Precipitate
Effect of precipitates on phase transformation behavior of Ti-49 at.% Ni film, 305
Pulse shape factors
Pulsed photothermal modeling of composite samples based on transmission-line theory of heat conduction, 58
Pulsed laser deposition
Pulsed laser deposition of ilmenite $FeTiO_3$ epitaxial thin film onto sapphire substrate, 114
Pyridine-borane
Influence of single-source precursors on PACVD-derived boron carbonitride thin films, 154

Quaterthiophenes
Morphological and spectroscopic studies of thin films of quaterthiophenes having extra bulky terminal groups, 137

r.f. plasma
Influence of single-source precursors on PACVD-derived boron carbonitride thin films, 154
Raman scattering
Characterization of laser ablated silicon thin films, 102
Reaction kinetics
Positive-ionic and neutral-molecular desorptions by temperature-programmed heating of a thin film of lithium bromide, 225
Reactive sputter deposition
Properties of aluminium oxide thin films deposited by reactive magnetron sputtering, 240

Scanning electron microscopy
Field-effect-transistor and real-space-transfer behaviors by double-heterojunction doped channel, 265
Secondary ion mass spectrometry (SIMS)
Surface OH group governing adsorption properties of metal oxide films, 220
Self-bias
Influence of single-source precursors on PACVD-derived boron carbonitride thin films, 154
Semiconductors
Electrical and optical phototransformation properties in As doped Se thin films, 314
Silicon substrate
Preparation of nitrogen-containing carbon films by electrolysis of organic solutions, 34
Single-source precursors
Growth of AlN films using hydrazidoalane single-source precursors, 200
Solar cells
The crystal structure of CdS–CdTe thin film heterojunction solar cells, 299
Sol-gel process
Formation of ultra-thin ceramic TiO_2 films by the Langmuir–Blodgett technique – a two-dimensional sol-gel process at the air–water interface, 284

Sol-gel processing
The sol-gel preparation and AFM study of spinel $CoFe_2O_4$ thin film, 109
Sol-gel, film
Sol-gel preparation of $Ti_{1-x}V_xO_2$ solid solution film electrodes with conspicuous photoresponse in the visible region, 123
Solid solution
Sol-gel preparation of $Ti_{1-x}V_xO_2$ solid solution film electrodes with conspicuous photoresponse in the visible region, 123
Spectroscopy
Morphological and spectroscopic studies of thin films of quaterthiophenes having extra bulky terminal groups, 137
Spinel
The sol-gel preparation and AFM study of spinel $CoFe_2O_4$ thin film, 109
Sputtering
Phase change of sputtered $LaNi_5$ thin films due to hydrogenation, 78
Structural analysis of Co–Cr alloy films by X-ray diffraction, 95
Crystallization behavior of r.f.-sputtered TiNi thin films, 194
Phase transition and properties of Ti–Al–N thin films prepared by r.f.-plasma assisted magnetron sputtering, 203
Effect of precipitates on phase transformation behavior of Ti-49 at.% Ni film, 305
Stacked elemental layer precursor
$CuInSe_2$ films produced by graphite box annealing of multilayer precursors, 44
Structural properties
Structural, compositional and photoluminescence characteristics of $CuInSe_2$ thin films prepared by close-spaced vapor transport, 10
Structural analysis of Co–Cr alloy films by X-ray diffraction, 95
Metastable phase diagram of Ti–Ti–N(O) films ($C_{Si} < 30$ at.%), 129
Solid single-source metal organic chemical vapor deposition of yttria-stabilized zirconia, 165
Sulphides
A study of the effects of ammonium salts on chemical bath deposited zinc sulfide thin films, 148
Surface energy
Spring constants of composite ceramic/gold cantilevers for scanning probe microscopy, 249
Surface morphology
Nanomechanical measurements on polymers using contact mode atomic force microscopy, 258
Surface roughness
Tailoring of a smooth polycrystalline gold surface as a suitable anchoring site for a self-assembled monolayer, 142
Surface segregation
Phase change of sputtered $LaNi_5$ thin films due to hydrogenation, 78
Surface-enhanced Raman spectroscopy
Interaction of copper(I)-polypyrrole complexes prepared by depositing–dissolving copper onto and from polypyrroles, 233

Tetrahedral amorphous carbon
Electrical properties of nitrogen incorporated tetrahedral amorphous carbon films, 74
Tetrahedral amorphous carbon film
Pulsed photothermal modeling of composite samples based on transmission-line theory of heat conduction, 58
Thermal conductivity
Pulsed photothermal modeling of composite samples based on transmission-line theory of heat conduction, 58
Thermal characterization of anisotropic thin dielectric films using harmonic Joule heating, 160
Thermal desorption
Positive-ionic and neutral-molecular desorptions by temperature-programmed heating of a thin film of lithium bromide, 225
Thickness dependence
Thickness dependence of the anisotropy in thermal expansion of PMDA-ODA and BPDA-PDA thin films, 68
Thin films
Thickness dependence of the anisotropy in thermal expansion of PMDA-ODA and BPDA-PDA thin films, 68
Morphological and spectroscopic studies of thin films of quaterthiophenes having extra bulky terminal groups, 137
$(Ti_{1-x}Al_x)N$ films
Phase transition and properties of Ti–Al–N thin films prepared by r.f.-plasma assisted magnetron sputtering, 203
Thin tungsten films
An ellipsometric study of W thin films deposited on Si, 216
TiO_2 films
Formation of ultra-thin ceramic TiO_2 films by the Langmuir–Blodgett technique – a two-dimensional sol-gel process at the air–water interface, 284
Titanium nitride
Metastable phase diagram of Ti–Ti–N(O) films ($C_{Si} < 30$ at.%), 129
Titanium nitride barrier
Characteristics of TiN barrier layer against Cu diffusion, 290
Titanium oxide
Sol-gel preparation of $Ti_{1-x}V_xO_2$ solid solution film electrodes with conspicuous photoresponse in the visible region, 123
Transission electron microscopy
Characterization of laser ablated silicon thin films, 102
AlN films grown by electric field induced flux of Al cations, 117
Effect of precipitates on phase transformation behavior of Ti-49 at.% Ni film, 305
Crystallization and decrease in resistivity on heat treatment of amorphous indium tin oxide thin films prepared by d.c. magnetron sputtering, 309
Transmission-line theory
Pulsed photothermal modeling of composite samples based on transmission-line theory of heat conduction, 58

Triazaborabicyclodecane
Influence of single-source precursors on PACVD-derived boron carbonitride thin films, 154
Tribology
Spring constants of composite ceramic/gold cantilevers for scanning probe microscopy, 249

Ultrathin silica film
Nanometer pores in ultrathin silica films prepared by self-assembly of organic spacers in an alkylsiloxane monolayer, 209

Vanadium oxide
Sol-gel preparation of $Ti_{1-x}V_xO_2$ solid solution film electrodes with conspicuous photoresponse in the visible region, 123

Work function
Positive-ionic and neutral-molecular desorptions by temperature-programmed heating of a thin film of lithium bromide, 225

X-ray diffraction
Phase change of sputtered $LaNi_5$ thin films due to hydrogenation, 78
Structural analysis of Co–Cr alloy films by X-ray diffraction, 95
Characterization of laser ablated silicon thin films, 102
Fabrication and characterization of heteropolyanion Langmuir–Blodgett films, 277
The crystal structure of CdS–CdTe thin film heterojunction solar cells, 299
Effect of precipitates on phase transformation behavior of Ti-49 at.% Ni film, 305
X-ray photoelectron spectroscopy
Interaction of copper(I)-polypyrrole complexes prepared by depositing–dissolving copper onto and from polypyrroles, 233

Zinc
A study of the effects of ammonium salts on chemical bath deposited zinc sulfide thin films, 148
Zirconium
Solid single-source metal organic chemical vapor deposition of yttria-stabilized zirconia, 165
ZnSSe
ZnS_xSe_{1-x} heteroepitaxial growth on GaP by metalorganic vapor phase epitaxy, 1